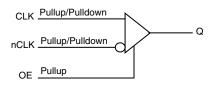
## **General Description**

830S21I-01 is a 1-to-1 Differential-to- LVCMOS/ LVTTL translator and a member of the family of High Performance Clock Solutions from IDT. The differential input is highly flexible and can accept the following input types: LVPECL, LVDS, LVHSTL, SSTL and HCSL. The small 8-lead SOIC footprint makes this device ideal for use in applications with limited board space.

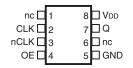
### Features

- One LVCMOS/LVTTL output
- Differential CLK, nCLK input pair
- CLK, nCLK pair can accept the following differential input levels: LVPECL, LVDS, LVHSTL, SSTL, HCSL
- Maximum output frequency: 350MHz
- Part-to-part skew: 525ps (maximum)
- Additive phase jitter, RMS: 0.11ps (typical)
- Small 8 lead SOIC package saves board space
- Full 3.3V and 2.5V operating supply
- -40°C to 85°C ambient operating temperature
- Available in lead-free (RoHS 6) package

### Block Diagram



#### **Pin Assignment**



830S21I-01

8-Lead SOIC 3.9mm x 4.9mm x 1.375mm package body M Package Top View

## Table 1. Pin Descriptions

Number	Name	T	уре	Description
1, 6	nc	Unused		No connect.
2	CLK	Input	Pullup/ Pulldown	Non-inverting differential clock input.
3	nCLK	Input	Pullup/ Pulldown	Inverting differential clock input.
4	OE	Input	Pullup	Output enable pin. See Table 3. LVCMOS / LVTTL interface levels.
5	GND	Power		Power supply ground.
7	Q	Output		Single-ended clock output. LVCMOS / LVTTL interface levels.
8	V <sub>DD</sub>	Power		Positive supply pin.

NOTE: Pullup and Pulldown refer to internal input resistors. See Table 2, Pin Characteristics, for typical values.

## **Table 2. Pin Characteristics**

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
C <sub>IN</sub>	Input Capacitance			4		pF
R <sub>PULLUP</sub>	Input Pullup Resistor			51		kΩ
R <sub>PULLDOWN</sub>	Input Pulldown Resistor			51		kΩ
C <sub>PD</sub>	Power Dissipation Capacitance	V <sub>DD</sub> = 3.465V		10		pF
OPD		V <sub>DD</sub> = 2.625V		8		pF
D		$V_{DD} = 3.3V$		10		Ω
R <sub>OUT</sub>	Output Impedance	V <sub>DD</sub> = 2.5V		12		Ω

## **Function Tables**

#### Table 3. OE Configuration Table

Input	
OE	Operation
0	Output Q is in a high-impedance state.
1 (default)	Output Q is enabled.

## **Absolute Maximum Ratings**

NOTE: Stresses beyond those listed under *Absolute Maximum Ratings* may cause permanent damage to the device. These ratings are stress specifications only. Functional operation of product at these conditions or any conditions beyond those listed in the *DC Characteristics or AC Characteristics* is not implied. Exposure to absolute maximum rating conditions for extended periods may affect product reliability.

Item	Rating
Supply Voltage, V <sub>DD</sub>	4.6V
Inputs, V <sub>I</sub>	-0.5V to V <sub>DD</sub> + 0.5V
Outputs, V <sub>O</sub>	-0.5V to V <sub>DD</sub> + 0.5V
Package Thermal Impedance, $\theta_{JA}$	93.1°C/W (0 mps)
Storage Temperature, T <sub>STG</sub>	-65°C to 150°C

### **DC Electrical Characteristics**

#### Table 4A. Power Supply DC Characteristics, $V_{DD}$ = 3.3V $\pm$ 5%, $T_{A}$ = -40°C to $85^{\circ}C$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V <sub>DD</sub>	Positive Supply Voltage		3.135	3.3	3.465	V
I <sub>DD</sub>	Power Supply Current				12	mA

#### Table 4B. Power Supply DC Characteristics, $V_{DD} = 2.5V \pm 5\%$ , $T_A = -40^{\circ}C$ to $85^{\circ}C$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V <sub>DD</sub>	Positive Supply Voltage		2.375	2.5	2.625	V
I <sub>DD</sub>	Power Supply Current				11	mA

#### Table 4C. LVCMOS/LVTTL DC Characteristics, V\_{DD} = $3.3V \pm 5\%$ or $2.5V \pm 5\%$ , T<sub>A</sub> = -40°C to $85^{\circ}C$

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
V	Input Lligh Voltage	V <sub>DD</sub> = 3.3V	2.2		V <sub>DD</sub> + 0.3	V
V <sub>IH</sub>	Input High Voltage	V <sub>DD</sub> = 2.5V	1.7		V <sub>DD</sub> + 0.3	V
V <sub>IL</sub>	Input Low Voltogo	V <sub>DD</sub> = 3.3V	-0.3		0.8	V
	Input Low Voltage	V <sub>DD</sub> = 2.5V	-0.3		0.7	V
I <sub>IH</sub>	Input High Current	$V_{DD} = V_{IN} = 3.465 V \text{ or } 2.625 V$			10	μA
IIL	Input Low Current	$V_{DD} = 3.465 V \text{ or } 2.625 V, V_{IN} = 0 V$	-150			μA
V	Output Lligh Voltage, NOTE 1	V <sub>DD</sub> = 3.3V	2.6			V
V <sub>OH</sub>	Output High Voltage; NOTE 1	V <sub>DD</sub> = 2.5V	1.8			V
V <sub>OL</sub>	Output Low Voltage; NOTE 1	V <sub>DD</sub> = 3.3V or 2.5V			0.5	V

NOTE 1: Outputs terminated with 50 $\Omega$  to V<sub>DD</sub>/2. See Parameter Measurement Information, *Output Load Test Circuit diagrams.* 

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
I <sub>IH</sub>	Input High Current	$V_{DD} = V_{IN} = 3.465V \text{ or } 2.625V$			150	μA
IIL	Input Low Current	$V_{DD} = 3.465V \text{ or } 2.625V, V_{IN} = 0V$	-150			μA
V <sub>PP</sub>	Peak-to-Peak Voltage; NOTE 1		0.15		1.5	V
V <sub>CMR</sub>	Common Mode Input Voltage; NOTE 1, 2		GND + 0.5		V <sub>DD</sub> – 0.85	V

Table 4D. Differential DC Characteristics,  $V_{DD} = 3.3V \pm 5\%$  or  $2.5V \pm 5\%$ ,  $T_A = -40^{\circ}$ C to  $85^{\circ}$ C

NOTE 1:  $V_{IL}$  should not be less than -0.3V.

NOTE 2: Common mode input voltage is defined as VIH.

### **AC Electrical Characteristics**

Table 5A. AC Characteristics,  $V_{DD} = 3.3V \pm 5\%$ ,  $T_A = -40^{\circ}C$  to  $85^{\circ}C$ 

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
f <sub>MAX</sub>	Output Frequency			350		MHz
t <sub>PD</sub>	Propagation Delay, NOTE 1		0.95		1.95	ns
<i>t</i> sk(pp)	Part-to-Part Skew; NOTE 2, 3				525	ps
<i>t</i> jit	Buffer Additive Phase jitter, RMS; refer to Additive Phase Jitter Section	350MHz, Integration Range (12kHz – 20MHz)		0.11		ps
t <sub>R</sub> / t <sub>F</sub>	Output Rise/Fall Time	20% to 80%	85		500	ps
odc	Output Duty Cycle	<i>f</i> ≤266MHz	47		53	%
t <sub>EN</sub>	Output Enable Time; NOTE 4				8	ns
t <sub>DIS</sub>	Output Disable Time; NOTE 4				8	ns

NOTE: Electrical parameters are guaranteed over the specified ambient operating temperature range, which is established when device is mounted in a test socket with maintained transverse airflow greater than 500 lfpm. Device will meet specifications after thermal equilibrium has been reached under these conditions.

NOTE 1: Measured from the differential input crossing point to the output at  $V_{DD}/2$ .

NOTE 2: Defined as skew between outputs on different devices operating at the same supply voltage and with equal load conditions. Using the same type of input on each device, the output is measured at  $V_{DD}/2$ .

NOTE 3: This parameter is defined in accordance with JEDEC Standard 65.

NOTE 4: This parameter is guaranteed by characterization. Not tested in production.

Symbol	Parameter	Test Conditions	Minimum	Typical	Maximum	Units
f <sub>MAX</sub>	Output Frequency			350		MHz
t <sub>PD</sub>	Propagation Delay, NOTE 1		1		2	ns
<i>t</i> sk(pp)	Part-to-Part Skew; NOTE 2, 3				550	ps
<i>t</i> jit	Buffer Additive Phase Jitter, RMS; refer to Additive Phase Jitter Section	350MHz, Integration Range (12kHz – 20MHz)		0.11		ps
t <sub>R</sub> / t <sub>F</sub>	Output Rise/Fall Time	20% to 80%	125		500	ps
odc	Output Duty Cycle	<i>f</i> ≤266MHz	47		53	%
t <sub>EN</sub>	Output Enable Time; NOTE 4				8	ns
t <sub>DIS</sub>	Output Disable Time; NOTE 4				8	ns

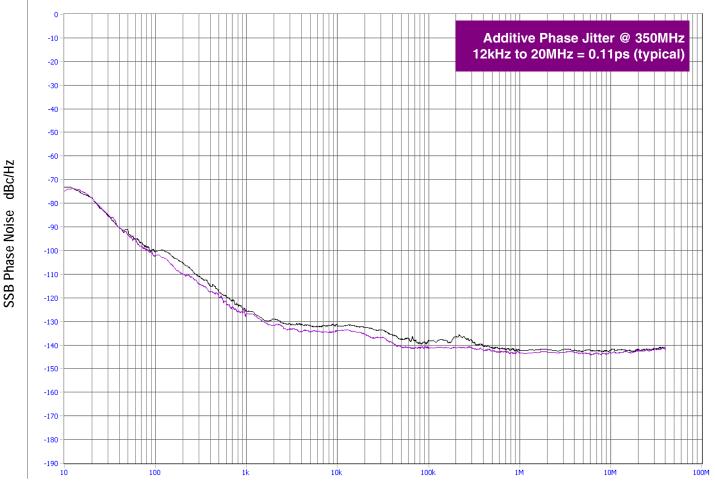
#### Table 5B. AC Characteristics, $V_{DD}$ = 2.5V $\pm$ 5%, $T_{A}$ = -40°C to 85°C

For NOTES, see Table 5A above.

## **Additive Phase Jitter**

The spectral purity in a band at a specific offset from the fundamental compared to the power of the fundamental is called the *dBc Phase Noise*. This value is normally expressed using a Phase noise plot and is most often the specified plot in many applications. Phase noise is defined as the ratio of the noise power present in a 1Hz band at a specified offset from the fundamental frequency to the power value of the fundamental. This ratio is expressed in decibels (dBm) or a ratio of the power in the 1Hz band to the power in the fundamental. When the required offset is

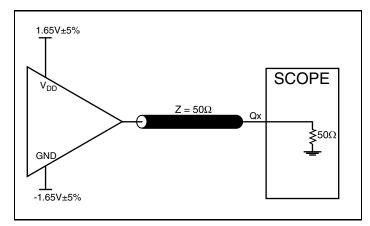
specified, the phase noise is called a *dBc* value, which simply means dBm at a specified offset from the fundamental. By investigating jitter in the frequency domain, we get a better understanding of its effects on the desired application over the entire time record of the signal. It is mathematically possible to calculate an expected bit error rate given a phase noise plot.



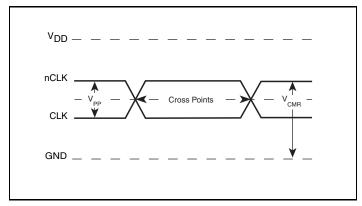
Offset Frequency (Hz)

As with most timing specifications, phase noise measurements has issues relating to the limitations of the equipment. Often the noise floor of the equipment is higher than the noise floor of the device. This is illustrated above. The device meets the noise floor of what is shown, but can actually be lower. The phase noise is dependent on the input source and measurement equipment.

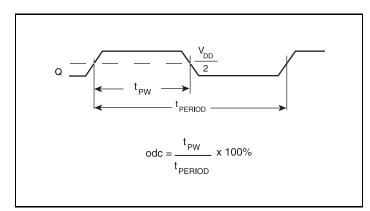
**Parameter Measurement Information** 



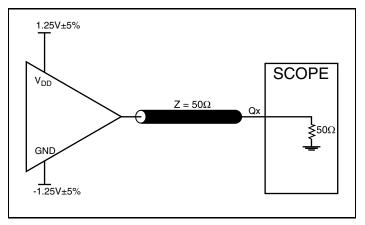
3.3V Core/3.3V LVCMOS Output Load AC Test Circuit



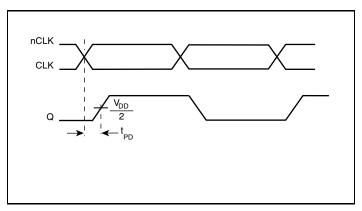
**Differential Input Level** 



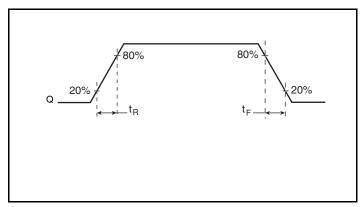
Output Duty Cycle/Pulse Width/Period



2.5V Core/2.5V LVCMOS Output Load AC Test Circuit



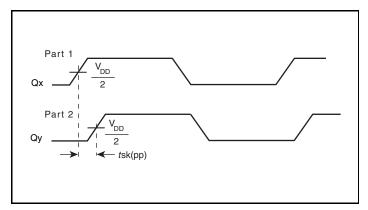
**Propagation Delay** 



**Output Rise/Fall Time** 

# RENESAS

## Parameter Measurement Information, continued



Part-to-Part Skew

# **Application Information**

### Wiring the Differential Input to Accept Single Ended Levels

*Figure 1* shows how the differential input can be wired to accept single ended levels. The reference voltage V\_REF =  $V_{DD}/2$  is generated by the bias resistors R1, R2 and C1. This bias circuit should be located as close as possible to the input pin. The ratio of R1 and R2 might need to be adjusted to position the V\_REF in the center of the input voltage swing. For example, if the input clock swing is only 2.5V and  $V_{DD}$  = 3.3V, V\_REF should be 1.25V and R2/R1 = 0.609.

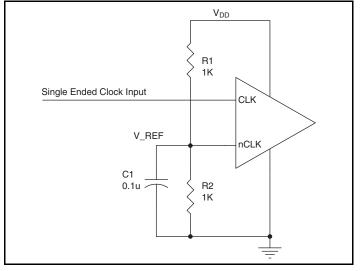
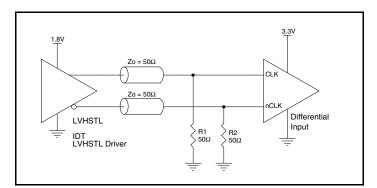
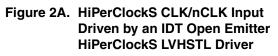


Figure 1. Single-Ended Signal Driving Differential Input

### **Differential Clock Input Interface**

The CLK /nCLK accepts LVDS, LVPECL, LVHSTL, SSTL, HCSL and other differential signals. Both V<sub>SWING</sub> and V<sub>OH</sub> must meet the V<sub>PP</sub> and V<sub>CMR</sub> input requirements. *Figures 2A to 2F* show interface examples for the HiPerClockS CLK/nCLK input driven by the most common driver types. The input interfaces suggested here are examples only. Please consult with the vendor of the driver





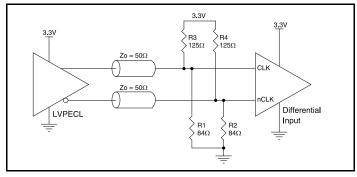


Figure 2C. HiPerClockS CLK/nCLK Input Driven by a 3.3V LVPECL Driver

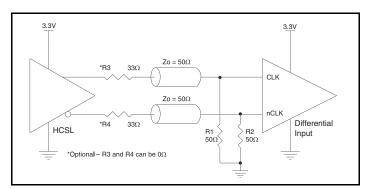


Figure 2E. HiPerClockS CLK/nCLK Input Driven by a 3.3V HCSL Driver

component to confirm the driver termination requirements. For example, in Figure 2A, the input termination applies for IDT HiPerClockS open emitter LVHSTL drivers. If you are using an LVHSTL driver from another vendor, use their termination recommendation.

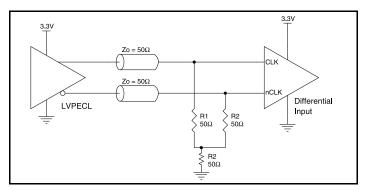


Figure 2B. HiPerClockS CLK/nCLK Input Driven by a 3.3V LVPECL Driver

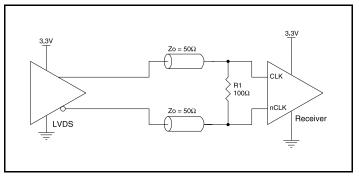


Figure 2D. HiPerClockS CLK/nCLK Input Driven by a 3.3V LVDS Driver

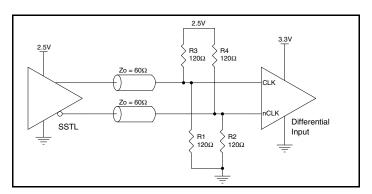


Figure 2F. HiPerClockS CLK/nCLK Input Driven by a 2.5V SSTL Driver

## **Reliability Information**

#### Table 6. $\theta_{\text{JA}}$ vs. Air Flow Table for a 8 Lead SOIC

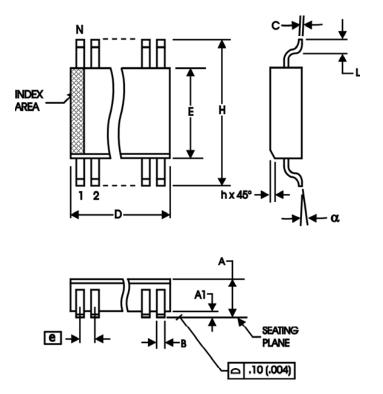
$\theta_{JA}$ vs. Air Flow					
Meters per Second	0	1	2.5		
Multi-Layer PCB, JEDEC Standard Test Boards	93.1°C/W	84.3°C/W	79.6°C/W		

#### **Transistor Count**

The transistor count for 830S21I-01 is: 214

## Package Outline and Package Dimensions

Package Outline - M Suffix for 8 Lead SOIC



# **Ordering Information**

#### Table 8. Ordering Information

Part/Order Number	Marking	Package	Shipping Packaging	Temperature
830S21AMI-01LF	S21AI01L	"Lead-Free" 8 Lead SOIC	Tube	-40°C to 85°C
830S21AMI-01LFT	S21AI01L	"Lead-Free" 8 Lead SOIC	Tape & Reel	-40°C to 85°C

# **Revision History**

Revision Date	Description of Change
December 10, 2015	<ul> <li>Removed ICS Chip and HiPerClockS under General Description.</li> <li>Removed ICS in the part numbers.</li> <li>Removed LF note at the bottom of the Ordering Information table.</li> <li>Removed the quantity of 2500 from the Tape &amp; Reel in the Ordering information table.</li> <li>Updated datasheet header and footer.</li> </ul>

